



### 30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

-33 A

#### **Features**

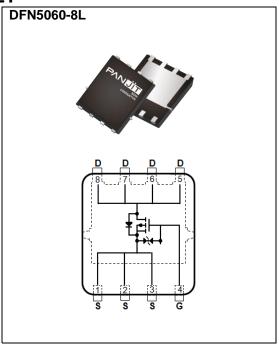
- RDS(ON), VGS@-10V, ID@-20A<18.8m $\Omega$
- RDS(ON), VGS@-4.5V, ID@-10A<30.7m $\Omega$
- 100% UIS tested
- Reliable and Rugged
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: DFN5060-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.08 grams



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETE	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V <sub>DS</sub>	-30	V	
Gate-Source Voltage		$V_{GS}$	±25	V	
Continuous Drain Current(Note 3)	T <sub>C</sub> =25°C	l <sub>D</sub>	-33	·	
	T <sub>C</sub> =100°C		-24	Α	
Pulsed Drain Current(Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	-98		
Power Dissipation	T <sub>C</sub> =25°C	D-	33	W	
	T <sub>C</sub> =100°C	Po	17		
Continuous Drain Current(Note 4)	T <sub>A</sub> =25°C	l <sub>D</sub>	-10.5	А	
	T <sub>A</sub> =70°C		-8.8		
Power Dissipation	T <sub>A</sub> =25°C	7	3.3	W	
	T <sub>A</sub> =70°C	Po	2.3		
Single Pulse Avalanche Energy <sup>(Note 5)</sup>		Eas	42	mJ	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~175	°C	
Thermal Resistance <sup>(Note 4)</sup>	Junction to Case	R <sub>0JC</sub>	4.5	°C/W	
	Junction to Ambient	$R_{\theta JA}$	45		





### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA		-	-	V	
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-1	-1.8	-2.5	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-20A	-	15	18.8	mΩ	
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-10A	-	23.6	30.7		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V	-	-	-1	uA	
0.11.0	I <sub>GSS</sub>	V <sub>GS</sub> =±25V, V <sub>DS</sub> =0V	-	-	±10	uA	
Gate-Source Leakage Current		V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V	-	-	±1		
Dynamic <sup>(Note 6)</sup>							
Total Gate Charge	$Q_g$	\/ 04\/ L 00A	-	22	-	nC	
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =-24V, I <sub>D</sub> =-20A,	-	3	-		
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =-10V	-	7	-		
Input Capacitance	Ciss	.,	-	1012	-	pF	
Output Capacitance	Coss	V <sub>DS</sub> =-25V, V <sub>GS</sub> =0V,	-	145	-		
Reverse Transfer Capacitance	Crss	f=1MHz	-	121	-		
Gate resistance	Rg	f=1MHz	-	10.4	-	Ω	
Turn-On Delay Time	td <sub>(on)</sub>	N 04N 1 00A	-	7	-	ns	
Turn-On Rise Time	tŗ	V <sub>DS</sub> =-24V, I <sub>D</sub> =-20A,	-	3	-		
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}$ =-10V, $R_{G}$ =3 $\Omega$	-	36	-		
Turn-Off Fall Time	tf	(14016-2)	-	40	-		
Drain-Source Diode							
Diode Forward Current	Is	Tc=25°C	-	-	-33	A	
Pulsed Diode Forward Current	I <sub>SM</sub>	1C=25 C	-	-	-98		
Diode Forward Voltage	V <sub>SD</sub>	Is=-20A, V <sub>G</sub> S=0V	-	-0.9	-1.3	V	
Reverse Recovery Time	Trr	V <sub>GS</sub> =0V, I <sub>S</sub> =-20A	-	16	-	ns	
Reverse Recovery Charge	Qrr	dl <sub>s</sub> /dt=100A/us	-	8	-	nC	

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I<sub>AS</sub>=-13A, V<sub>DD</sub>=-30V, V<sub>GS</sub>=-10V, Starting T<sub>J</sub>=25°C.
- 6. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

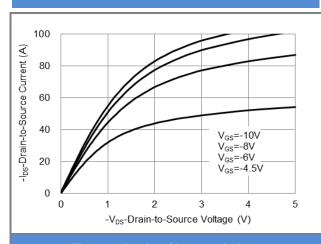


Fig.1 On-Region Characteristics

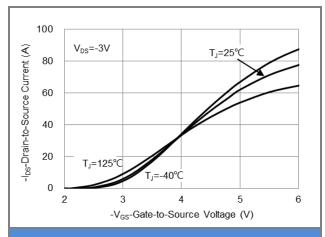


Fig.2 Transfer Characteristics

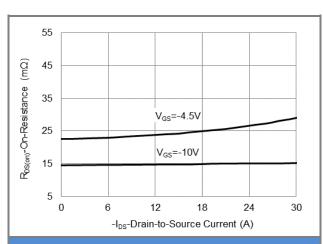


Fig.3 On-Resistance vs. Drain Current

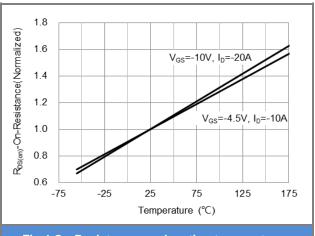


Fig.4 On-Resistance vs. Junction temperature

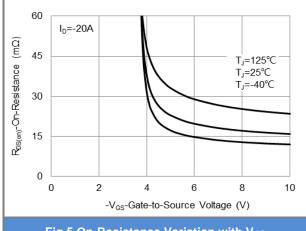
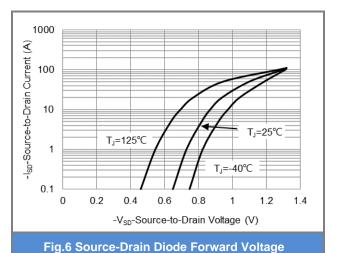


Fig.5 On-Resistance Variation with V<sub>GS</sub>







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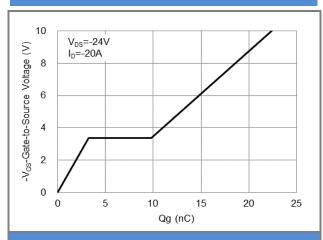


Fig.7 Gate-Charge Characteristics

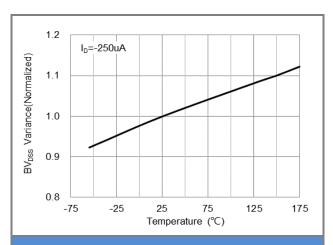


Fig.8 Breakdown Voltage Variation vs. Temperature

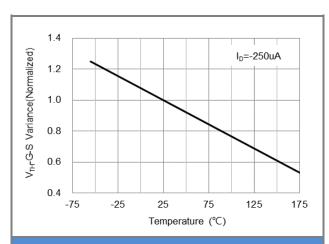


Fig.9 Threshold Voltage Variation with Temperature

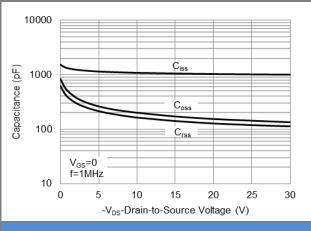
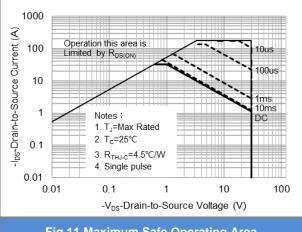


Fig.10 Capacitance vs. Drain-Source Voltage





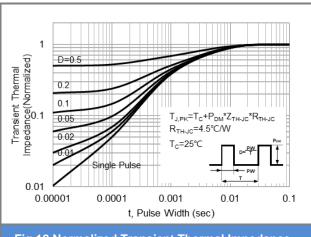


Fig.12 Normalized Transient Thermal Impedance

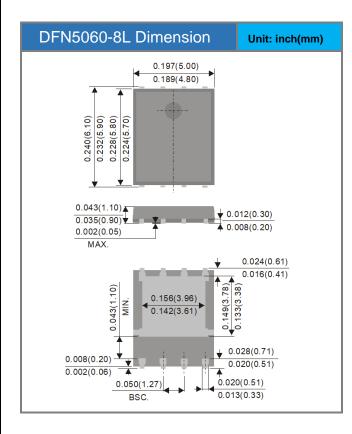


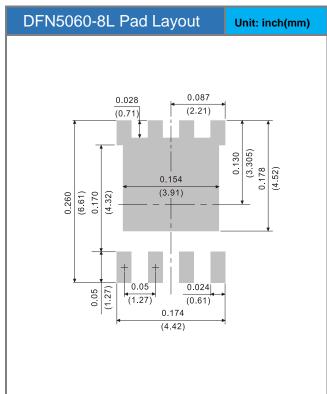


#### **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking	
PJQ5439E-AU	DFN5060-8L	3K pcs / 13" reel	Q5439E	

### **Packaging Information & Mounting Pad Layout**









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